# () IDT.

## SPREAD SPECTRUM CLOCK SYNTHESIZER

## DATASHEET

## IDT5P50901/2/3/4

## Description

The IDT5P50901/2/3/4 is a family of 1.8V low power, spread spectrum clock generators capable of reducing EMI radiation from an input clock. Spread spectrum technique is capable of reducing the harmonic frequency amplitude peaks by several dB.

## **Ordering Information**

#### **Input Frequency**

10 to 25 MHz - 5P50901NBGI/5P50901DVGI 20 to 50 MHz - 5P50902NBGI/5P50902DVGI 40 to 100 MHz - 5P50903NBGI/5P50903DVGI 80 to 170 MHz - 5P50904NBGI/5P50904DVGI

## **Features**

- 8-pin DFN package (2x2mm)
   8-pin MSOP package (3x4.9mm)
- Provides a spread spectrum output clock
- Input frequency range of 10 to 170 MHz
- Output frequency range of 10 to 170 MHz
- Center and down spread
- Peak reduction by 8 dB to 16 dB typical on 3rd through 19th odd harmonics
- Low EMI feature can be disabled
- Operating voltage of 1.8 V, 2.5 or 3.3V
- RoHS 6 compliant package

## **Spread Modulation Frequency Table**

Part Number	Input (MHz)	Modulation (kHz)	Input (MHz)	Modulation (kHz)	Modulation Frequency (kHz)
5P50901	10	27	25	67.5	ICLK*27/10000
5P50902	20	27	50	67.5	ICLK*27/20000
5P50903	40	27	100	67.5	ICLK*27/40000
5P50904	80	27	170	57.4	ICLK*27/80000

## **Block Diagram**



## **Pin Assignment**



8-pin DFN

## **Spread Direction and Percentage Select Table**

S2	S1	S0	Spread Direction	Spread Percentage
0	0	0	OFF	
0	0	1	Center	±0.25
0	1	0	Center	±0.5
0	1	1	Center	±1.0
1	0	0	Center	±1.5
1	0	1	Center	±2.0
1	1	0	Down	-0.5
1	1	1	Down	-1.0

## **Pin Description**

Pin Number	Pin Name	Pin Type	Pin Description
1	ICLK	Input	Input clock.
2	VDD	Power	Voltage supply. Connect to 1.8 V $\pm$ 0.1 V, 2.5 V $\pm$ 10% or 3.3 V $\pm$ 10%,
3	S0	Input	Function select 0 input. Selects spread amount and direction per table above. Internal pull-down resistor.
4	S1	Input	Function select 1 input. Selects spread amount and direction per table above. Internal pull-down resistor.
5	S2	Input	Function select 2 input. Selects spread amount and direction per table above. Internal pull-down resistor.
6	GND	Power	Connect to ground.
7	CLKOUT	Output	Clock output.
8	VDD	Power	Voltage supply. Connect to 1.8 V $\pm$ 0.1 V, 2.5 V $\pm$ 10% or 3.3 V $\pm$ 10%

## **External Components**

#### **Decoupling Capacitor**

As with any high-performance mixed-signal IC, the IDT5P50901/2/3/4 must be isolated from system power supply noise to perform optimally.

A decoupling capacitor of  $0.01\mu$ F must be connected between each VDD and the PCB ground plane.

#### **Series Termination Resistor**

Clock output traces over one inch should use series termination. To series terminate a  $50\Omega$  trace (a commonly used trace impedance), place a  $33\Omega$  resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is  $20\Omega$ 

#### **External Clock Input**

This device operates from an external clock input and as such does not have a on chip oscillator circuit.

## **Spread Spectrum Profile**

The IDT5P50901/2/3/4 is a low EMI clock generator using an optimized frequency slew rate algorithm to facilitate down stream tracking of zero delay buffers and other PLL devices.

The modulation rate is directly relate to the input clock frequency.

For input frequency ICLK, then use the modulation frequency indicated for the part below.



#### **PCB Layout Recommendations**

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1) The  $0.01\mu$ F decoupling capacitors should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitors and VDD pins. The PCB trace to VDD pins should be kept as short as possible, as should the PCB trace to the ground via.

2) To minimize EMI, the  $33\Omega$  series termination resistor (if needed) should be placed close to the clock output.

3) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the IDT5P50901/2/3/4. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

## **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the IDT5P50901/2/3/4. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	-0.5 V to 5.0 V
All Inputs	-0.5 V to VDD +0.5 V
Ambient Operating Temperature	-40 to +85° C
Storage Temperature	-50 to +150° C
Junction Temperature	125° C
Soldering Temperature	260° C

## **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature	-40		+85	°C
Power Supply Voltage VDD (measured in respect to GND)	+1.7	+1.8	+1.9	V
	+2.25	+2.5	+2.75	V
	+2.97	+3.3	+3.63	V

## **DC Electrical Characteristics**

#### Unless stated otherwise, **VDD** = $1.8 \text{ V} \pm 0.1 \text{ V}$ . Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		1.7	1.8	1.9	V
Input High Voltage	V <sub>IH</sub>	ICLK, S2:S0	VDD x 0.8		VDD + 0.3	V
Input Low Voltage	V <sub>IL</sub>	ICLK, S2:S0	GND		VDD x 0.2	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	VDD x 0.75	VDD		V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 12 mA		GND	VDD x 0.25	V
IDD		No load	See table page 6			
Input Capacitance				5		pF
Load Capacitance				5		pF
Internal Pull-down Resistor	R <sub>PD</sub>	S1:S0		200	260	kΩ

Unless stated otherwise, VDD = 2.5 V  $\pm$ 10%. Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		2.25	2.5	2.75	V
Input High Voltage	V <sub>IH</sub>	ICLK, S2:S0	VDD x 0.8		VDD + 0.3	V
Input Low Voltage	V <sub>IL</sub>	ICLK, S2:S0	GND		VDD x 0.2	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -25 mA	VDD x 0.9	VDD		V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 25 mA		GND	VDD x 0.1	V
IDD		No load	See table page 6			
Input Capacitance				5		pF
Load Capacitance				5		pF
Internal Pull-down Resistor	R <sub>PD</sub>	S1:S0		200	260	kΩ

Unless stated otherwise, VDD = 3.3 V ±10%. Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		2.97	3.3	3.63	V
Input High Voltage	V <sub>IH</sub>	ICLK, S2:S0	VDD x 0.8		VDD + 0.3	V
Input Low Voltage	V <sub>IL</sub>	ICLK, S2:S0	GND		VDD x 0.2	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -33 mA	VDD x 0.9	VDD		V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 33 mA		GND	VDD x 0.1	V
IDD		No load	See table page 6			
Input Capacitance				5		pF
Load Capacitance				5		pF
Internal Pull-down Resistor	R <sub>PD</sub>	S1:S0		200	260	kΩ

#### **Operational IDD**



## **AC Electrical Characteristics**

Unless stated otherwise, VDD = 1.8 V ±0.1 V, 2.5 V ±10% or 3.3 V ±10%. Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Output Clock Duty Cycle			45	50	55	%
		1.8V ±0.1V, >130MHz	40	50	60	
Output Rise Time	t <sub>OR</sub>	20% to 80%, Note 1		1.2		ns
Output Fall Time	t <sub>OF</sub>	80% to 20%, Note 1		1.2		ns
Spread Spectrum Modulation		10 to 25 MHz input (IDT5P50901)	27		67.5	kHz
Rate		20 to 50 MHz input (IDT5P50902)	27		67.5	kHz
		40 to 100 MHz input (IDT5P50903)	27		67.5	kHz
		80 to 170 MHz input (IDT5P50904)	27		57.3	kHz
Jitter Cycle to Cycle		Cycle to cycle jitter		150		ps
Output Settling Time		Note 2			3.0	ms

Note 1: Measured with 5 pF load

Note 2: Time between VDD rising above minimum operating voltage and stable frequency output

## Package Outline and Package Dimensions (8-pin DFN 2x2mm, 0.5mm pitch)

Package dimensions are kept current with JEDEC Publication No. 95,



	Millimeters				
Symbol	Min	Max			
A	0.80	1.00			
A1	0	0.05			
A3	0.20 Re	eference			
b	0.20	0.30			
N		8			
N <sub>D</sub>	4				
N <sub>E</sub>		0			
D	2.00	BASIC			
E	2.00	BASIC			
е	0.50	BASIC			
D2	1.05	1.25			
E2	0.45	0.65			
L	0.20 0.40				
aaa	0.15				
bbb	0.10				
CCC	0.	10			

#### Marking Diagram (8DFN)



#### Notes:

- 1. #### is the last four numbers of the lot number.
- 2. Dot indicates pin 1.
- 3. "G" designates Pb (lead) free package.

## Package Outline and Package Dimensions (8-pin MSOP, 3.00 mm Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		Incl	nes*	
Symbol	Min	Max	Min	Max	
A		1.10		0.043	
A1	0	0.15	0	0.006	
A2	0.79	0.97	0.031	0.038	
b	0.22	0.38	0.008	0.015	
С	0.08	0.23	0.003	0.009	
D	3.00 E	BASIC	0.118 BASIC		
E	4.90 E	BASIC	0.193 BASIC		
E1	3.00 E	BASIC	0.118	BASIC	
е	0.65	Basic	0.0256	Basic	
L	0.40	0.80	0.016	0.032	
α	<b>0</b> °	<b>8</b> °	<b>0</b> °	8°	
aaa	-	0.10	-	0.004	

\*For reference only. Controlling dimensions in mm.



#### Marking Diagram (8 MSOP)



Notes:

1.YYWW is the assembly date code.

- 2. Dot indicates pin 1.
- 3. "G" designates Pb (lead) free package.
- 4. "I" designates industrial temperature range.

## **Ordering Information**

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5P50901NBGI8		Tape and Reel	8-pin DFN	-40° C to +85° C
5P50901DVGI		Tube	8-pin MSOP	-40° C to +85° C
5P50901DVGI8		Tape and Reel	8-pin MSOP	-40° C to +85° C
5P50902NBGI8		Tape and Reel	8-pin DFN	-40° C to +85° C
5P50902DVGI		Tube	8-pin MSOP	-40° C to +85° C
5P50902DVGI8	000 pogoo 7 9	Tape and Reel	8-pin MSOP	-40° C to +85° C
5P50903NBGI8	see pages 7,8	Tape and Reel	8-pin DFN	-40° C to +85° C
5P50903DVGI		Tube	8-pin MSOP	-40° C to +85° C
5P50903DVGI8		Tape and Reel	8-pin MSOP	-40° C to +85° C
5P50904NBGI8		Tape and Reel	8-pin DFN	-40° C to +85° C
5P50904DVGI		Tube	8-pin MSOP	-40° C to +85° C
5P50904DVGI8		Tape and Reel	8-pin MSOP	-40° C to +85° C

#### "G" after the two-letter package code denotes Pb-Free configuration, RoHS compliant.

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## **Revision History**

Rev.	Date	Originator	Description of Change
Α	6/28/11	R. WIllner	Initial release.
В	6/30/11	R. Willner	Correct modulation rate on 5P50904, rise/fall time definition.
С	07/29/11	R. Willner	Added "Internal Pull-down Resistor" spec to DC char tables
D	10/07/11	R. Willner	Correct typographical errors.
Е	05/14/12	R. Willner	Changed max Supply Voltage VDD rating from 7.0V to 5.0V
F	08/21/12	R. Willner	<ol> <li>Changed "Output High/Low Voltage" specs; conditions and min/max values for 1.8V DC electrical characteristics</li> <li>Added an additional line for "Output Clock Duty Cycle" in AC char table to include conditions and values for 1.8V</li> </ol>

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#### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru\_4

moschip.ru\_6 moschip.ru\_9